# YJ Planar Fast Recovery Diode Die Specification

600V 10A, Fast recovery diode die based on silicon planar process Part No.: FRD10A600AS-290A

# **Main Products Characterstics**

- Average forward current: IF(AV) = 10A
- Maximum operating junction temperature: Tj = 150 °C
- Planar Construction
- Top metal: Al



## **Maximum Ratings**

Parameter	Symbol	Rating
Repetitive peak reverse voltage	V <sub>RRM</sub>	600V
Average forward current	I <sub>F(AV)</sub>	10A
Non-repetitive peak surge current (tp = 8.3 ms, halfwave, 1 cycle)	I <sub>FSM</sub>	100A
Storage temperature range	T <sub>stg</sub>	-40 to +150 °C
Maximum operating junction temperature	Τj	150 °C

### Static Electrical Characteristics (Ta = 25°C)

Parameter	Symbol	Value	
		Spec	Typical
Reverse breakdown voltage I <sub>R</sub> = 50uA	$V_{BR}$	630V	680V
Maximum forward voltage drop $I_F$ = 10A, Pulse Test: tp = 380 $\mu s, \ \delta \leqslant 2\%$	$V_{F}$	1.6V	1.45V
Reverse Recovery Time I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>rr</sub> =0.25A	Trr	35ns	28ns
Maximum reverse current $V_R = V_{RRM}$ Pulse Test: tp = 10 ms, $\delta \le 2\%$	I <sub>R</sub>	2uA	0.02uA

#### **Device Schematics and Outline Drawing**



#### **Important Notice**

Specification apply to die only. Actual performance may degrade when assembled.	Recommended Storage Environment:
Yangjie Electronics does not guarantee device performance after assembly. All operating parameters must be validated for each customer application by customer's technical experts.	Store in original container, in dessicated nitrogen, with no contamination.
	Shelf life for parts stored in above condition is 2 years.
Data sheet information is subjected to change without notice.	If the storage is done in normal atmosphere shelf life is reduced to 6 months.

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